



HV16

8-Channel High Voltage Analog Switch

Ordering Information

V _{PP}	V _{NN}	V _{SIG}	Package Options				
			24-pin Ceramic Side-brazed DIP*	Die	36-pin Leaded Ceramic Chip Carrier*	24-pin Plastic DIP	28-lead Plastic Chip Carrier
+70V	-70V	110V P-P	HV1614C	HV1614X	HV1614CS	HV1614P	HV1614PJ
+80V	-80V	130V P-P	HV1616C	HV1616X	HV1616CS	HV1616P	HV1616PJ

* Consult factory for Cerdip and Ceramic LCC availability.

Features

- ☐ HVC MOS[®] technology
- ☐ Up to 130V peak to peak switching capability
- ☐ Output On-resistance typically 40 ohms
- ☐ Low parasitic capacitances
- ☐ DC to 10MHz analog signal frequency
- ☐ 45 dB typical output off isolation at 5 MHz
- ☐ CMOS logic circuitry for low power and excellent noise immunity
- ☐ On-chip shift register and latch logic circuitry
- ☐ Surface mount package available

General Description

This device is an 8-channel high-voltage integrated circuit (HVIC) intended for use in applications requiring high voltage switching controlled by low voltage signals; e.g., ultrasound imaging and printers. Input data is shifted into an 8-bit shift register which can then be retained in an 8-bit latch. Using HVC MOS technology, this HVIC combines high voltage bi-lateral DMOS switches and low power CMOS logic to provide efficient control of high voltage analog signals.

Absolute Maximum Ratings*

V _{DD} Logic power supply voltage	-0.5V to +18V
V _{PP} - V _{NN} supply voltage	174V†
V _{PP} Positive high voltage supply	-0.5V to +90V†
V _{NN} Negative high voltage supply	+0.5V to -90V†
Logic input voltages	-0.5V to V _{DD} +0.3V
Analog signal range	V _{NN} to V _{PP}
Peak analog signal current/channel	1.5A
Storage temperature	-65°C to +150°C
Power dissipation	800mW

* Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability.

† For HV1616

Electrical Characteristics

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(over operating conditions, $V_{PP} = +80V$, $V_{NN} = -80V$ and $V_{DD} = 15V$ unless otherwise noted)*

DC Characteristics

Characteristics	Sym	0°C		+25°C			+70°C		Units	Test Conditions
		min	max	min	typ	max	min	max		
Switch (ON) Resistance	R_{ONS}		50		40	50		60	ohms	$I_{SW} = 5mA$, $V_{SIG} = 0V$
Switch (ON) Resistance	R_{ONS}		35		25	35		45	ohms	$I_{SW} = 200mA$, $V_{SIG} = 0V$
Switch (ON) Resistance	R_{ONS}		55		45	55		65	ohms	$V_{PP} = +50V$, $V_{NN} = -50V$, $I_{SW} = 5mA$, $V_{SIG} = 0V$
Switch (ON) Resistance	R_{ONS}		40		25	40		50	ohms	$V_{PP} = +50V$, $V_{NN} = -50V$, $I_{SW} = 200mA$, $V_{SIG} = 0V$
Switch (ON) Resistance Matching	ΔR_{ONS}		15			15		15	%	$V_{PP} = +50V$, $V_{NN} = -50V$, $I_{SW} = 5mA$, $V_{SIG} = 0V$
Switch Off Leakage	I_{SOL}		50		0.5	50		150	μA	$V_{SIG} = V_{PP} - 10V$ thru 10K Ω with 8 SWS in parallel
DC Offset Switch Off			500		100	500		500	mV	$R_L = 100K\Omega$
DC Offset Switch On			500		100	500		500	mV	$R_L = 100K\Omega$
Pole to Pole Switch Capacitance	C_{SW}		10		4.5	10		10	pF	DC Bias = 40V $f = 1MHz$
Logic Input Capacitance	C_{IN}				3.5				pF	
Pos. HV Supply Current	I_{PPQ}		200		50	200		200	μA	ALL SWS OFF
Neg. HV Supply Current	I_{NNQ}		-200		-50	-200		-200	μA	
Pos. HV Supply Current	I_{PPQ}				0.8	1.6			mA	1 SW ON, $I_{SW} = 5mA$, $V_{SIG} = 0V$
Neg. HV Supply Current	I_{NNQ}				-0.8	-1.6			mA	
Pos. HV Supply Current	I_{PPQ}				0.6	1.2			mA	$V_{PP} = +50V$, $V_{NN} = -50V$, 1 SW ON, $I_{SW} = 5mA$
Neg. HV Supply Current	I_{NNQ}				-0.6	-1.2			mA	
Switch Output Peak Current					1.5				A	$V_{SIG} \leq 0.1\%$ Duty Cycle, $f = 10KHz$
Logic Supply Average Current	I_{DD}				4	6			mA	$f_{CLK} = 3MHz$
Logic Supply Quiescent Current	I_{DDQ}				10	500			μA	
Data Out Source Current	I_{SOR}	0.7		0.8	0.9		0.7		mA	$V_{OUT} = V_{DD} - 0.7V$
Data Out Sink Current	I_{SINK}	0.7		0.8	0.9		0.7		mA	$V_{OUT} = 0.7V$

AC Characteristics

Characteristics	Sym	0°C		+25°C			+70°C		Units	Test Conditions
		min	max	min	typ	max	min	max		
Set Up Time Before $\overline{LE}$ Rises	t_{SD}			260					ns	
Time Width of $\overline{LE}$	t_{WLE}			300					ns	
Clock Delay Time to Data Out	t_{DO}				250	330			ns	
Turn On Time	t_{ON}		5.0		2.5	5.0		5.0	μs	$R_L = 10K\Omega$
Turn Off Time	t_{OFF}		10		5.0	10		10	μs	$R_L = 10K\Omega$
Off Isolation	KO			-35	-45				dB	Signal Freq. = 5MHz
Max Clock Freq	f_{CLK}					3.0			MHz	50% Duty Cycle $t_{DATA} = t_{CLK}/2$
Set Up Time Data to Clock	t_{SU}			0					ns	
Hold Time Data from Clock	t_h			35					ns	
Switch Crosstalk	K_{CR}				-45				dB	Signal Freq. = 5MHz

* For HV1616: For HV1614: $V_{PP} = +70V$, $V_{NN} = -70V$, and $V_{DD} = 15V$.

Operating Conditions

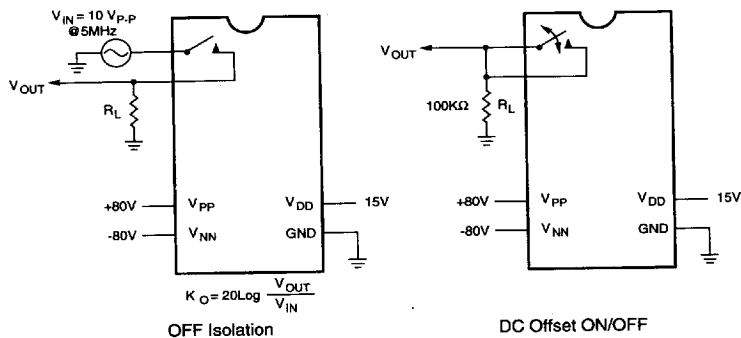
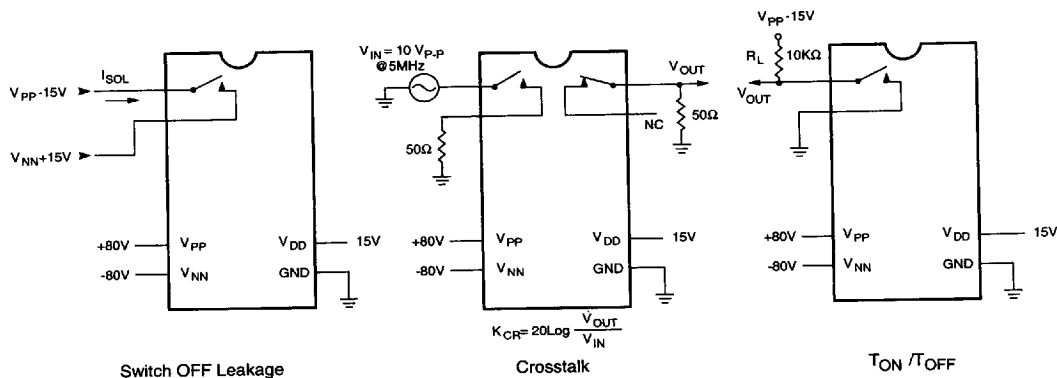
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Symbol	Parameter	Device		Value
		HV1614	HV1616	
V_{DD}	Logic power supply voltage	X	X	+10.0V to +15.5V
V_{PP}	Positive high voltage supply	X		+50V to +70V
			X	+50V to +80V
V_{NN}	Negative high voltage supply	X		-50V to -70V
			X	-50V to -80V
V_{IH}	High level input voltage	X	X	$V_{DD} - 2V$ to V_{DD}
V_{IL}	Low-level input voltage	X	X	0 to 2.0V
V_{SIG}	Analog signal voltage peak to peak	X	X	$V_{NN} + 15V$ to $V_{PP} - 15V$
T_A	Operating free air-temperature	X	X	0° to 70°C

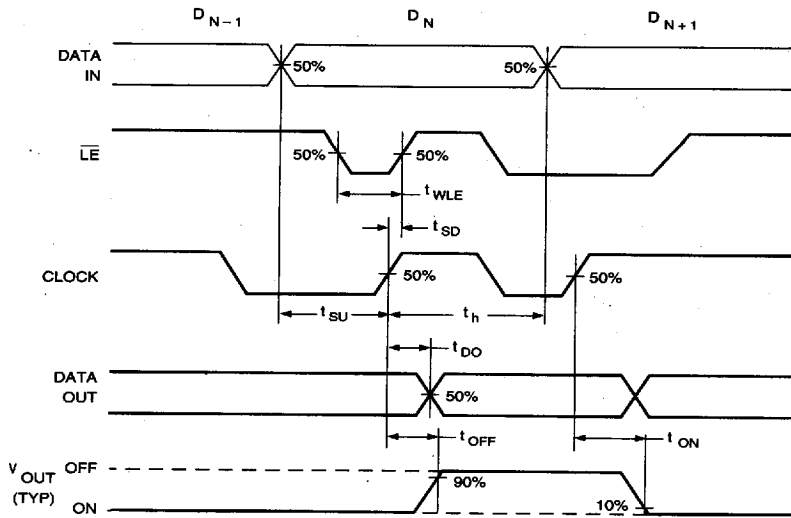
Notes:

- Power up/down sequence is arbitrary except GND must be powered-up first and powered-down last.
- V_{SIG} must be $V_{NN} \leq V_{SIG} \leq V_{PP}$ or floating during power up/down transition.

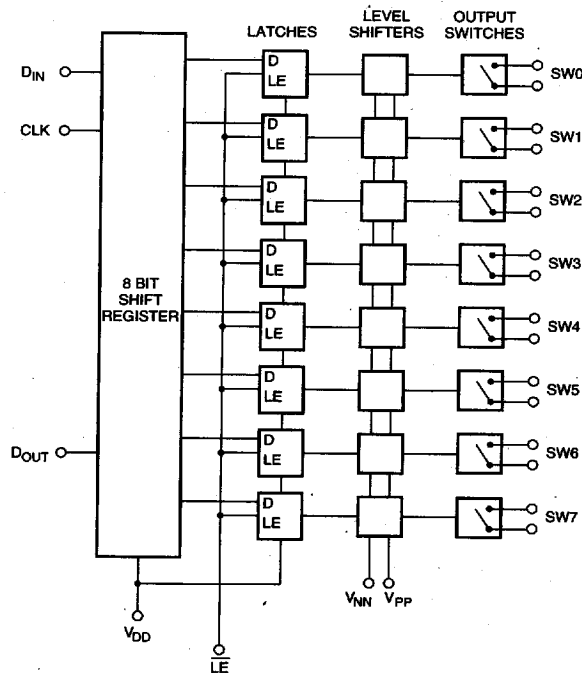
Test Circuits



Logic Timing Waveforms



Logic Diagram



Truth Table

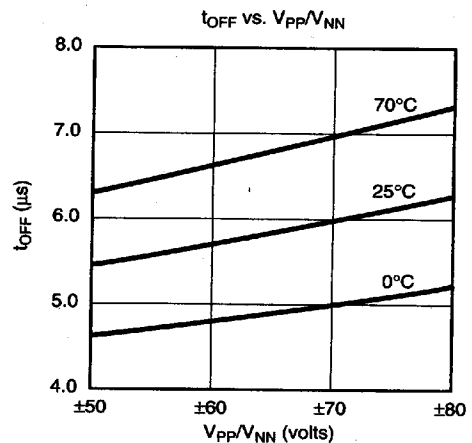
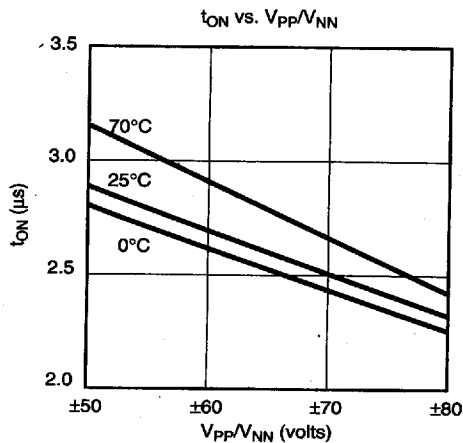
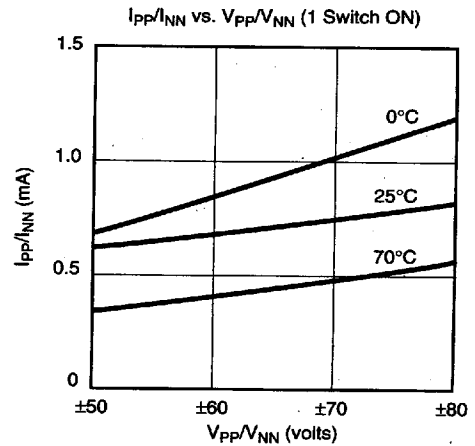
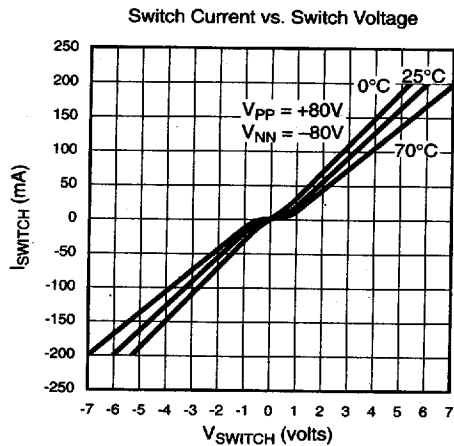
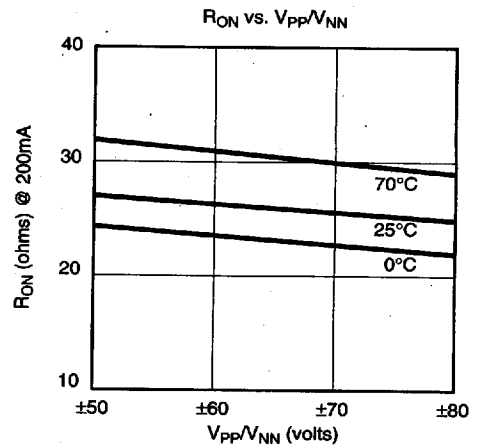
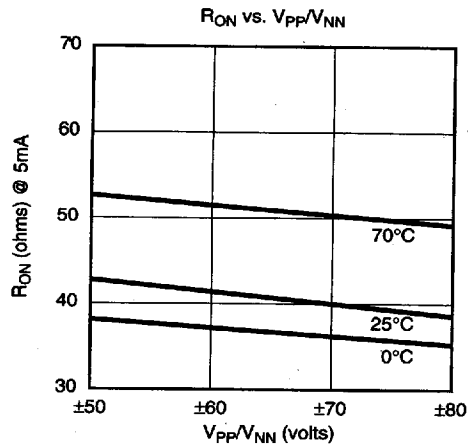
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D0	D1	D2	D3	D4	D5	D6	D7	$\overline{LE}$	SW0	SW1	SW2	SW3	SW4	SW5	SW6	SW7
L								L	OFF							
H								L	ON							
	L							L		OFF						
	H							L		ON						
		L						L			OFF					
		H						L			ON					
			L					L				OFF				
			H					L				ON				
				L				L					OFF			
				H				L					ON			
					L			L						OFF		
					H			L						ON		
						L		L							OFF	
						H		L							ON	
							L	L								OFF
							H	L								ON
X	X	X	X	X	X	X	X	H	HOLD PREVIOUS STATE							

Notes:

1. The eight switches operate independently.
2. Serial data is clocked in on the L $\rightarrow$ H transition CLK.
3. The switches go to a state retaining their present condition at the rising edge of LE. When $\overline{LE}$ is low the shift register data flows through the latch.
4. D_{OUT} is high when switch 7 is on.
5. Shift register clocking has no effect on the switch states if $\overline{LE}$ is H.

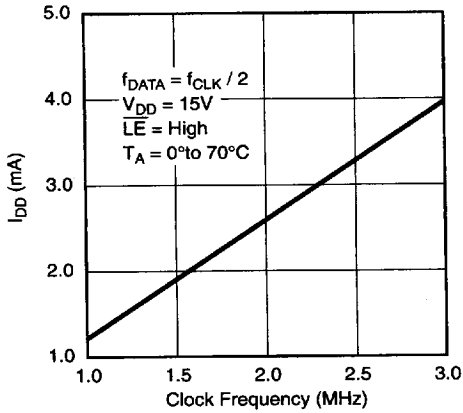
Typical Performance Curves



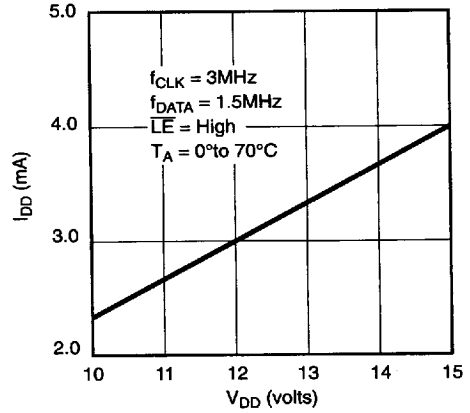
Typical Performance Curves

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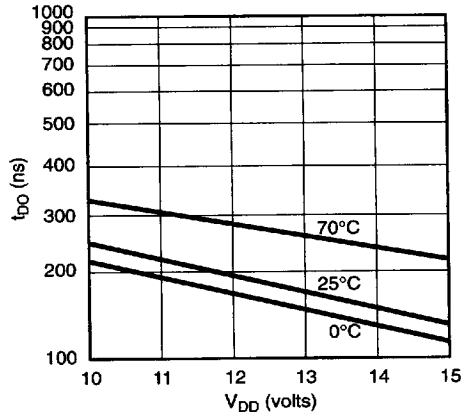
I_{DD} vs. Frequency



I_{DD} vs. V_{DD}



t_{DO} vs. V_{DD}



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Pin Configurations

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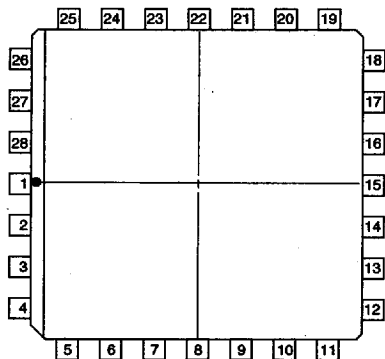
28-Pin J-Lead

Pin	Function	Pin	Function
1	SW3	15	N/C
2	SW3	16	D _{IN}
3	SW2	17	CLK
4	SW2	18	LE
5	N/C	19	D _{OUT}
6	N/C	20	SW7
7	SW1	21	SW7
8	SW1	22	SW6
9	SW0	23	SW6
10	SW0	24	N/C
11	V _{PP}	25	SW5
12	V _{NN}	26	SW5
13	GND	27	SW4
14	V _{DD}	28	SW4

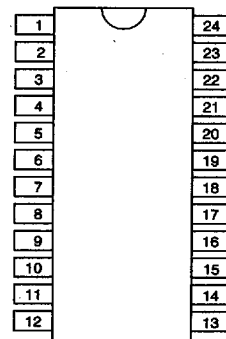
24-Pin DIP

Pin	Function	Pin	Function
1	SW3	13	D _{IN}
2	SW3	14	CLK
3	SW2	15	LE
4	SW2	16	D _{OUT}
5	SW1	17	SW7
6	SW1	18	SW7
7	SW0	19	SW6
8	SW0	20	SW6
9	V _{PP}	21	SW5
10	V _{NN}	22	SW5
11	GND	23	SW4
12	V _{DD}	24	SW4

Package Outlines



top view
28-pin J-lead Package



top view
24-pin DIP